



迈拓电子
MAITUO ELECTRONIC

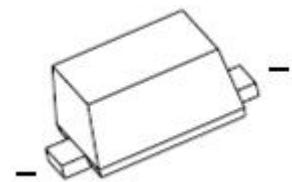
DESD7Z5.0 Plastic-Encapsulate Diodes



Bi-direction ESD Protection Diode

DESCRIPTION

Designed to protect voltage sensitive electronic components from ESD and other transients. Excellent clamping capability, low leakage, low capacitance, and fast response time provide best in class protection on designs that are exposed to ESD.



The combination of small size, low capacitance, and high level of ESD protection makes them a flexible solution for applications such as HDMI, Display Port TM, and MDDI interfaces. It is designed to replace multiplayer varistors (MLV) in consumer equipments applications such as mobile phone, notebook, PAD, STB, LCD TV etc.

SOD-723

FEATURES

- Bi-directional ESD protection of one line
- Low capacitance: 12pF(Typ.)
- Low reverse stand-off voltage: 5.0V
- Low reverse clamping voltage
- Low leakage current
- Excellent package: 1.00mm×0.6mm×0.55mm
- Fast response time
- JESD22-A114-B ESD Rating of class 3B per human body model
- IEC 61000-4-2 Level 4 ESD protection

APPLICATIONS

- Computers and peripherals
- PAD
- Audio and video equipment
- Cellular handsets and accessories
- Subscriber identity module(SIM) card protection
- Portable electronics
- Other electronics equipments communication systems

MARKING : H



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MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
IEC 61000-4-2 ESD Voltage	$V_{ESD}^{(1)}$	± 25	kV
Air Model		± 25	
Contact Model		± 25	
JESD22-A114-B ESD Voltage		Per Human Body Model	
ESD Voltage	Machine Model	± 16	
Peak Pulse Power	$P_{PP}^{(2)}$	50	W
Peak Pulse Current	$I_{PP}^{(2)}$	5	A
Lead Solder Temperature – Maximum (10 Second Duration)	T_L	260	°C
Operation Junction and Storage Temperature Range	T_J, T_{stg}	-55 ~ +150	°C

(1).Device stressed with ten non-repetitive ESD pulses.

(2).Non-repetitive current pulse 8/20μs exponential decay waveform according to IEC61000-4-5.

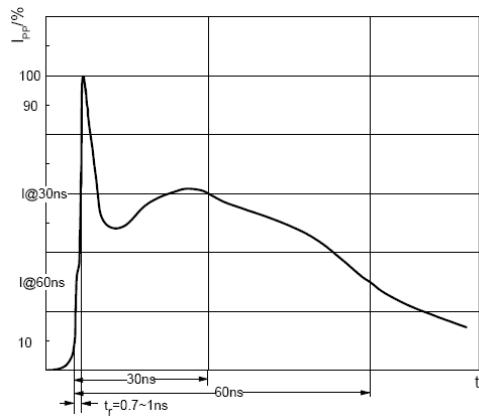
ESD standards compliance

IEC61000-4-2 Standard

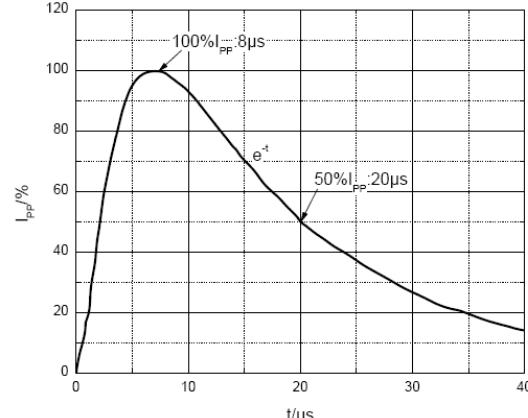
Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15

JESD22-A114-B Standard

ESD Class	Human Body Discharge V
0	0~249
1A	250~499
1B	500~999
1C	1000~1999
2	2000~3999
3A	4000~7999
3B	8000~15999



ESD pulse waveform according to IEC61000-4-2



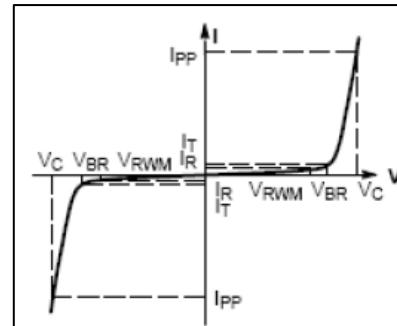
8/20μs pulse waveform according to IEC 61000-4-5



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ELECTRICAL PARAMETER

Symbol	Parameter
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Peak Pulse Current
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_R	Reverse Leakage Current @ V_{RWM}
V_{RWM}	Reverse Standoff Voltage



V-I characteristics for a Bi-directional TVS

ELECTRICAL CHARACTERISTICS($T_a=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse stand off voltage	$V_{RWM}^{(1)}$				5	V
Reverse leakage current	I_R	$V_{RWM}=5V$			0.1	μA
Breakdown voltage	$V_{(BR)}$	$I_T=1mA$	5.8		7.8	V
Clamping voltage	$V_C^{(2)}$	$I_{PP}=5A$			10	V
Junction capacitance	C_J	$V_R=0V, f=1MHz$		12	15	pF

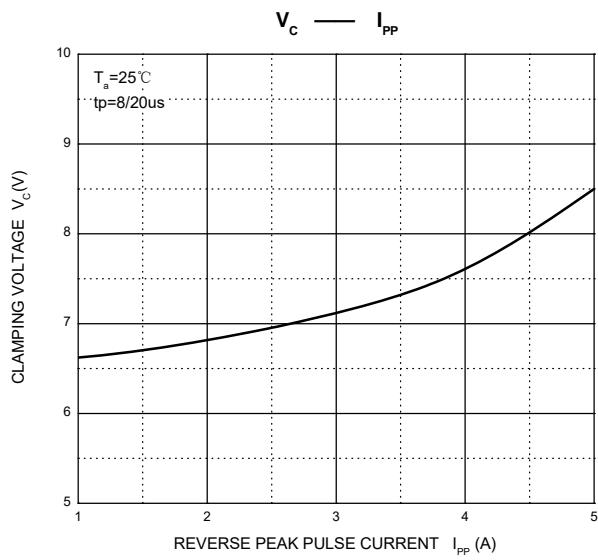
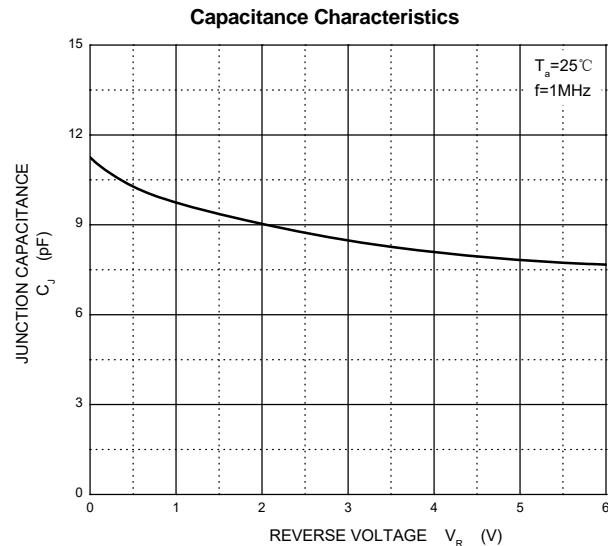
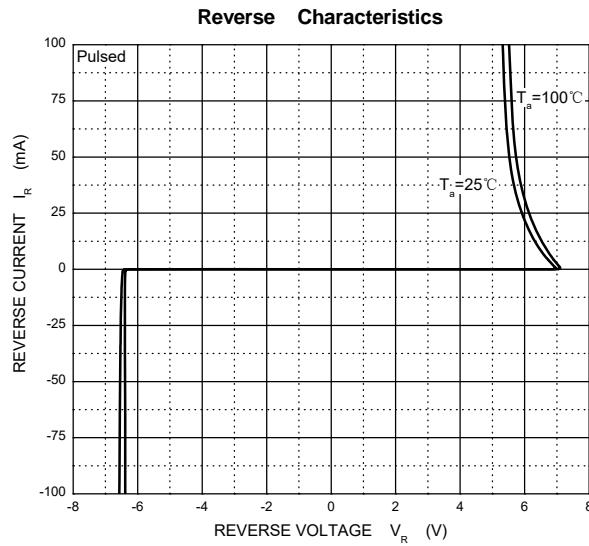
(1).Other voltages available upon request.

(2).Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5



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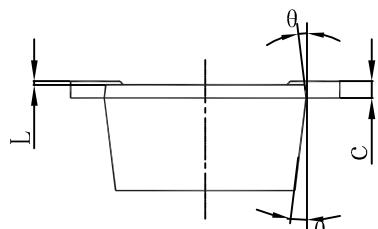
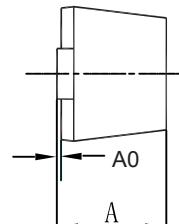
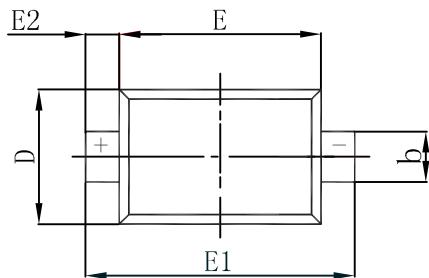
TYPICAL CHARACTERISTICS





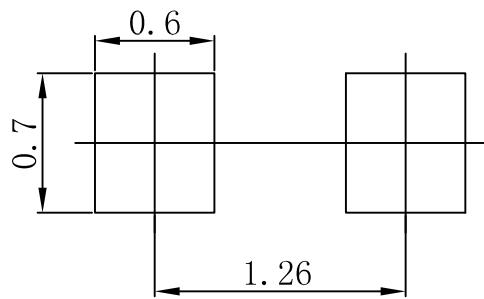
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SOD-723 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.450	0.550	0.018	0.022
A0	0.000	0.020	0.000	0.008
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	0.550	0.650	0.022	0.026
E	0.900	1.100	0.035	0.043
E1	1.300	1.500	0.051	0.059
E2	0.200 REF		0.008 REF	
L	0.010	0.070	0.001	0.003
θ	7° REF		7° REF	

SOD-723 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.